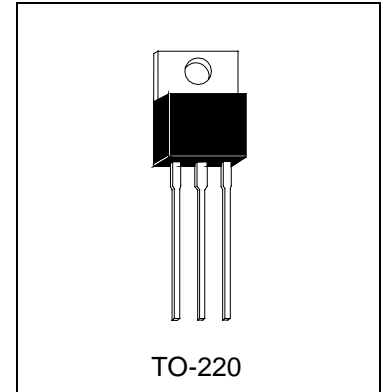




HTIP31C

NPN EPITAXIAL PLANAR TRANSISTOR



Description

The HTIP31C is designed for use in general purpose amplifier and switching applications.

Absolute Maximum Ratings (T_A=25°C)

- Maximum Temperatures
 - Storage Temperature -55 ~ +150 °C
 - Junction Temperature +150 °C Maximum
- Maximum Power Dissipation
 - Total Power Dissipation (T_C=25°C) 40 W
- Maximum Voltages and Currents
 - BV_{CBO} Collector to Base Voltage 100 V
 - BV_{CEO} Collector to Emitter Voltage 100 V
 - BV_{EBO} Emitter to Base Voltage 5 V
 - I_C Collector Current 3 A

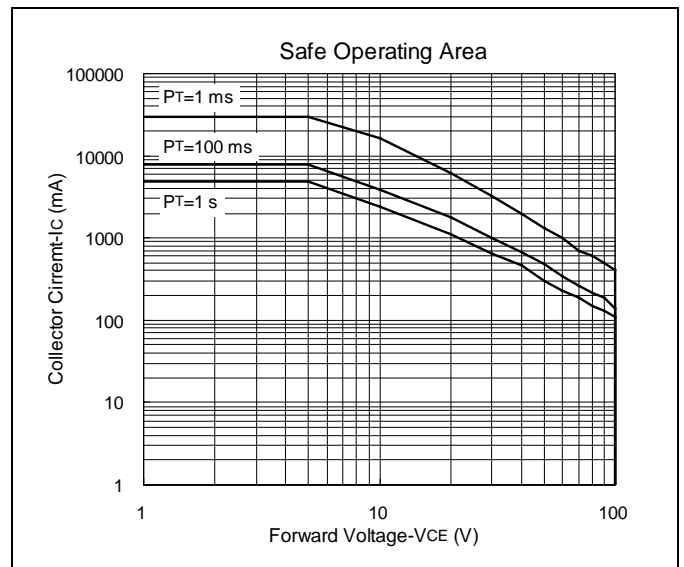
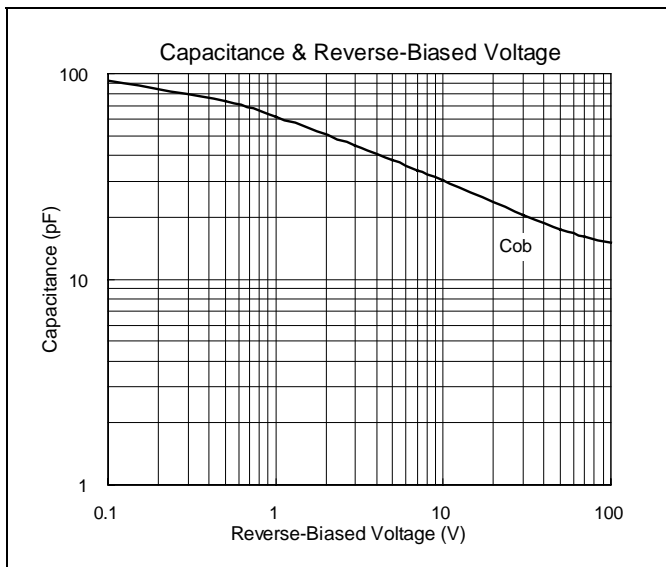
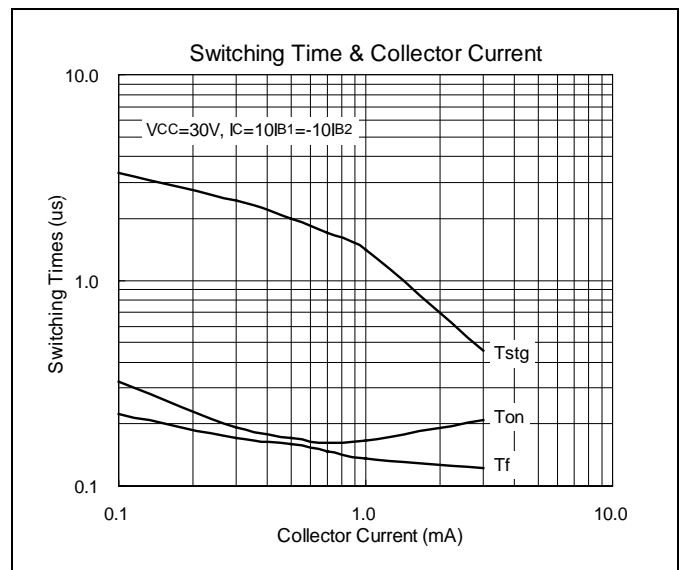
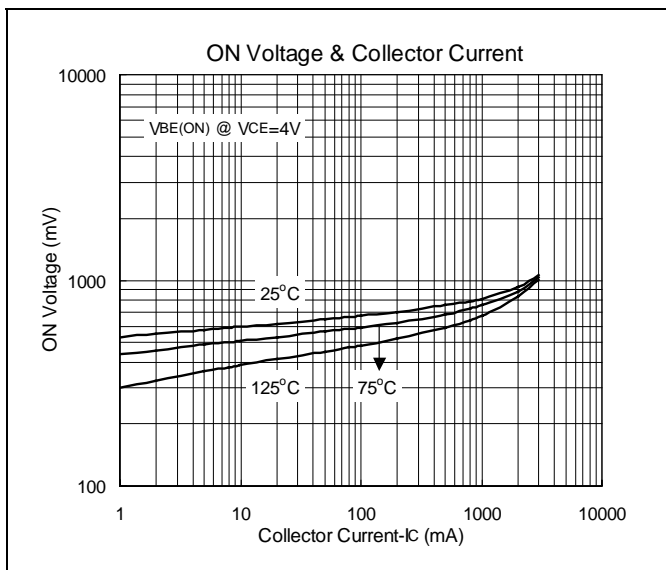
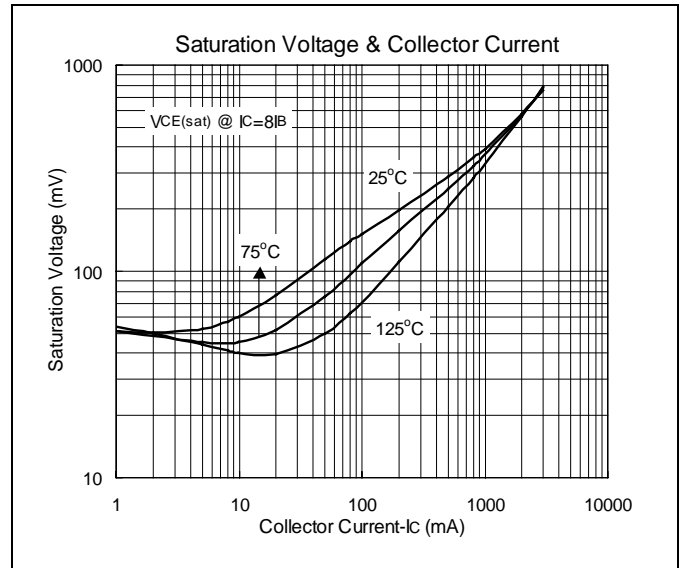
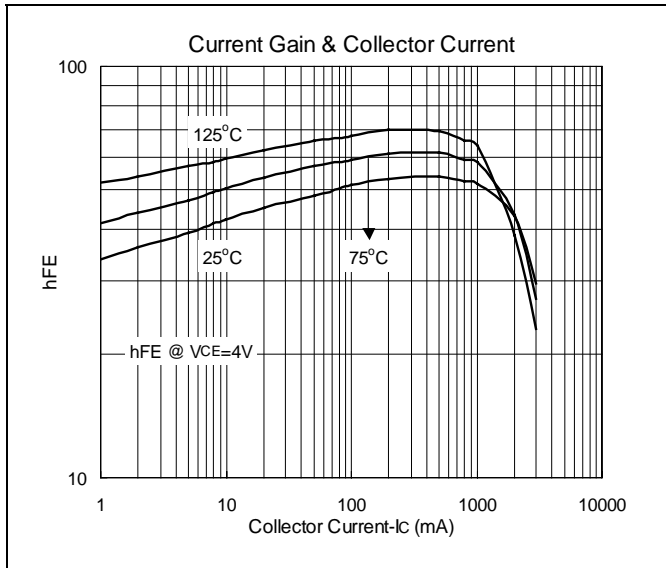
Electrical Characteristics (T_A=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	100	-	-	V	I _C =1mA, I _E =0
BV _{CEO}	100	-	-	V	I _C =30mA, I _C =0
I _{CES}	-	-	200	uA	V _{CE} =100V, I _B =0
I _{CEO}	-	-	300	uA	V _{CE} =60V, I _B =0
I _{EBO}	-	-	1	mA	V _{EB} =5V, I _C =0
*V _{CE(sat)}	-	-	1.2	V	I _C =3A, I _B =375mA
*V _{BE(on)}	-	-	1.8	V	I _C =3A, V _{CE} =4V
*h _{FE1}	25	-	-		I _C =1A, V _{CE} =4V
*h _{FE2}	10	-	50		I _C =3A, V _{CE} =4V
f _T	3	-	-	MHz	I _C =0.5A, V _{CE} =10V, f=1MHz

*Pulse Test: Pulse Width ≤380us, Duty Cycle ≤2%



Characteristics Curve





TO-220AB Dimension

3-Lead TO-220AB
 Plastic Package
 HSMC Package Code: E

Marking:

Pb Free Mark
 Pb-Free: "●" (Note)
 Normal: None

Date Code Control Code

Note: Green label is used for pb-free packing
 Pin Style: 1.Base 2 & Tab.Collector 3.Emitter
 Material:
 • Lead solder plating: Sn60/Pb40 (Normal), Sn/3.0Ag/0.5Cu or Pure-Tin (Pb-free)
 • Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

DIM	Min.	Max.
A	5.58	7.49
B	8.38	8.90
C	4.40	4.70
D	1.15	1.39
E	0.35	0.60
F	2.03	2.92
G	9.66	10.28
H	-	*16.25
I	-	*3.83
J	3.00	4.00
K	0.75	0.95
L	2.54	3.42
M	1.14	1.40
N	-	*2.54
O	12.70	14.27
P	14.48	15.87

*: Typical, Unit: mm

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Soldering Methods for HSMC's Products

1. Storage environment: Temperature=10°C~35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	$<3^{\circ}\text{C}/\text{sec}$	$<3^{\circ}\text{C}/\text{sec}$
Preheat		
- Temperature Min (T_{Smin})	100°C	150°C
- Temperature Max (T_{Smax})	150°C	200°C
- Time (min to max) (t_s)	60~120 sec	60~180 sec
T_{Smax} to T_L		
- Ramp-up Rate	$<3^{\circ}\text{C}/\text{sec}$	$<3^{\circ}\text{C}/\text{sec}$
Time maintained above:		
- Temperature (T_L)	183°C	217°C
- Time (t_L)	60~150 sec	60~150 sec
Peak Temperature (T_P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t_p)	10~30 sec	20~40 sec
Ramp-down Rate	$<6^{\circ}\text{C}/\text{sec}$	$<6^{\circ}\text{C}/\text{sec}$
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak temperature	Dipping time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec